FEATURES
AC and DC Characterized and Specified
  (K, B, T Grades)
128k Conversions per Second
1 MHz Full Power Bandwidth
500 kHz Full Linear Bandwidth
80 dB S/N+D (K, B, T Grades)
Twos Complement Data Format (Bipolar Mode)
Straight Binary Data Format (Unipolar Mode)
10 MΩ Input Impedance
8-Bit Bus Interface (See AD779 for 16-Bit Interface)
On-Board Reference and Clock
10 V Unipolar or Bipolar Input Range
Pin Compatible with AD678 12-Bit, 200 kSPS ADC
MIL-STD-883 Compliant Versions Available

FUNCTIONAL BLOCK DIAGRAM
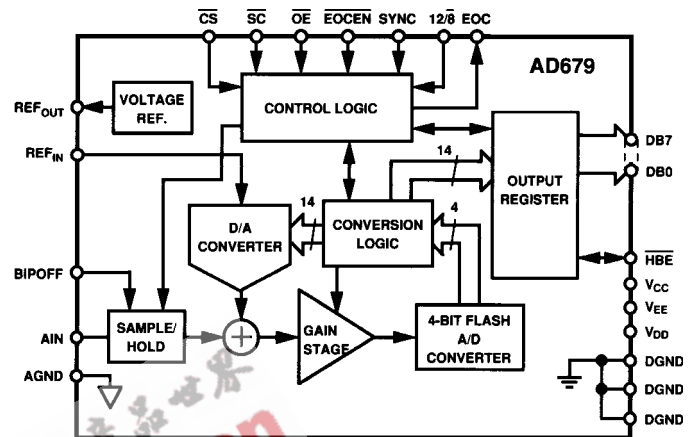
GENERAL DESCRIPTION

The AD679 is a complete, multipurpose 14-bit monolithic analog-to-digital converter, consisting of a sample-hold amplifier (SHA), a microprocessor compatible bus interface, a voltage reference and clock generation circuitry.

The AD679 is specified for ac (or "dynamic") parameters such as S/N+D ratio, THD and IMD which are important in signal processing applications. In addition, the AD679K, B and T grades are fully specified for dc parameters which are important in measurement applications.

The 14 data bits are accessed in two read operations (8+6), with left justification. Data format is straight binary for unipolar mode and twos complement binary for bipolar mode. The input has a full-scale range of 10 V with a full power bandwidth of 1 MHz and a full linear bandwidth of 500 kHz. High input impedance (10 MΩ) allows direct connection to unbuffered sources without signal degradation. Conversions can be initiated either under microprocessor control or by an external clock asynchronous to the system clock.

This product is fabricated on Analog Devices' BiMOS process, combining low power CMOS logic with high precision, low noise bipolar circuits; laser-trimmed thin-film resistors provide high accuracy. The converter utilizes a recursive subranging algorithm which includes error correction and flash converter circuitry to achieve high speed and resolution.

The AD679 operates from +5 V and ±12 V supplies and dissipates 560 mW (typ). 28-pin plastic DIP, ceramic DIP and 44 J-leaded ceramic surface mount packages are available.

*Protected by U.S. Patent Nos. 4,804,960; 4,814,767; 4,833,345; 4,250,445;
4,808,908; RE 30,586

PRODUCT HIGHLIGHTS

1. COMPLETE INTEGRATION: The AD679 minimizes external component requirements by combining a high speed sample-hold amplifier (SHA), ADC, 5 V reference, clock and digital interface on a single chip. This provides a fully specified sampling A/D function unattainable with discrete designs.

2. SPECIFICATIONS: The AD679K, B and T grades provide fully specified and tested ac and dc parameters. The AD679J, A and S grades are specified and tested for ac parameters; dc accuracy specifications are shown as typicals. DC specifications (such as INL, gain and offset) are important in control and measurement applications. AC specifications (such as S/N+D ratio, THD and IMD) are of value in signal processing applications.

3. EASE OF USE: The pinout is designed for easy board layout, and the two read output provides compatibility with 8-bit buses. Factory trimming eliminates the need for calibration modes or external trimming to achieve rated performance.

4. RELIABILITY: The AD679 utilizes Analog Devices' monolithic BiMOS technology. This ensures long term reliability compared to multichip and hybrid designs.

5. UPGRADE PATH: The AD679 provides the same pinout as the 12-bit, 200 kSPS AD678 ADC.

6. The AD679 is available in versions compliant with MIL-STD-883. Refer to the Analog Devices Military Products Databook or current AD679/883B data sheet for detailed specifications.

REV. C

AD679–SPECIFICATIONS

AC SPECIFICATIONS (T_{MIN} to T_{MAX}, V_{CC} = +12 V ± 5%, V_{EE} = −12 V ± 5%, V_{DD} = +5 V ± 10%, f_{SAMPLE} = 128 kSPS, f_{IN} = 10.009 kHz unless otherwise noted)[1]

Parameter	AD679J/A/S			AD679K/B/T			Units
	Min	Typ	Max	Min	Typ	Max	
SIGNAL-TO-NOISE AND DISTORTION (S/N+D) RATIO[2]							
−0.5 dB Input (Referred to −0 dB Input)	78	79		80	81		dB
−20 dB Input (Referred to −20 dB Input)	58	59		60	61		dB
−60 dB Input (Referred to −60 dB Input)	18	19		20	21		dB
TOTAL HARMONIC DISTORTION (THD)[3]							
@ +25°C		−90	−84		−90	−84	dB
		0.003	0.006		0.003	0.006	%
T_{MIN} to T_{MAX}		−88	−82		−88	−82	dB
		0.004	0.008		0.004	0.008	%
PEAK SPURIOUS OR PEAK HARMONIC COMPONENT		−90	−84		−90	−84	dB
FULL POWER BANDWIDTH		1			1		MHz
FULL LINEAR BANDWIDTH	500			500			kHz
INTERMODULATION DISTORTION (IMD)[4]							
2nd Order Products		−90	−84		−90	−84	dB
3rd Order Products		−90	−84		−90	−84	dB

DIGITAL SPECIFICATIONS (All device types T_{MIN} to T_{MAX}, V_{CC} = +12 V ± 5%, V_{EE} = −12 V ± 5%, V_{DD} = +5 V ± 10%)

Parameter		Test Conditions	Min	Max	Units
LOGIC INPUTS					
V_{IH}	High Level Input Voltage		2.0	V_{DD}	V
V_{IL}	Low Level Input Voltage		0	0.8	V
I_{IH}	High Level Input Current	V_{IN} = 5 V	−10	+10	µA
I_{IL}	Low Level Input Current	V_{IN} = 0 V	−10	+10	µA
C_{IN}	Input Capacitance			10	pF
LOGIC OUTPUTS					
V_{OH}	High Level Output Voltage	I_{OH} = 0.1 mA	4.0		V
		I_{OH} = 0.5 mA	2.4		V
V_{OL}	Low Level Output Voltage	I_{OL} = 1.6 mA		0.4	V
I_{OZ}	High Z Leakage Current	V_{IN} = 0 or 5 V	−10	+10	µA
C_{OZ}	High Z Output Capacitance			10	pF

NOTES
[1] f_{IN} amplitude = −0.5 dB (9.44 V p-p) bipolar mode full scale unless otherwise indicated. All measurements referred to a −0 dB (9.997 V p-p) input signal unless otherwise noted.
[2] See Figure 15 for higher frequencies and other input amplitudes.
[3] See Figures 13 and 14 for higher frequencies and other input amplitudes.
[4] f_A = 9.08 kHz, f_B = 9.58 kHz, with f_{SAMPLE} 100 kSPS. See Definition of Specifications section.

Specifications subject to change without notice.

REV. C

DC SPECIFICATIONS (T_{MIN} to T_{MAX}, V_{CC} = +12 V ± 5%, V_{EE} = –12 V ± 5%, V_{DD} = +5 V ± 10% unless otherwise noted)

Parameter	AD679J/A/S Min	Typ	Max	AD679K/B/T Min	Typ	Max	Units
TEMPERATURE RANGE							
J, K Grades	0		+70	0		+70	°C
A, B Grades	–40		+85	–40		+85	°C
S, T Grades	–55		+125	–55		+125	°C
ACCURACY							
Resolution	**14**			**14**			Bits
Integral Nonlinearity (INL)		±2			±1	**±2**	LSB
Differential Nonlinearity (DNL)	**14**			**14**			Bits
Unipolar Zero Error[1] (@ +25°C)		0.08			0.05	**0.07**	% FSR*
Bipolar Zero Error[1] (@ +25°C)		0.08			0.05	**0.07**	% FSR
Gain Error[1,2] (@ +25°C)		0.12			0.09	**0.11**	% FSR
Temperature Drift							
Unipolar Zero[3]							
J, K Grades		0.04			0.04	**0.05**	% FSR
A, B Grades		0.05			0.05	**0.07**	% FSR
S, T Grades		0.09			0.09	**0.10**	% FSR
Bipolar Zero[3]							
J, K Grades		0.02			0.02	**0.04**	% FSR
A, B Grades		0.04			0.04	**0.05**	% FSR
S, T Grades		0.08			0.08	**0.09**	% FSR
Gain[3]							
J, K Grades		0.09			0.09	**0.11**	% FSR
A, B Grades		0.10			0.10	**0.16**	% FSR
S, T Grades		0.20			0.20	**0.25**	% FSR
Gain[4]							
J, K Grades		0.04			0.04	**0.05**	% FSR
A, B Grades		0.05			0.05	**0.07**	% FSR
S, T Grades		0.09			0.09	**0.10**	% FSR
ANALOG INPUT							
Input Ranges							
Unipolar Mode	**0**		**+10**	**0**		**+10**	V
Bipolar Mode	**–5**		**+5**	**–5**		**+5**	V
Input Resistance		10			10		MΩ
Input Capacitance		10			10		pF
Input Settling Time			1.5			1.5	µs
Aperture Delay		10			10		ns
Aperture Jitter		150			150		ps
INTERNAL VOLTAGE REFERENCE							
Output Voltage[5]	**4.98**		**5.02**	**4.98**		**5.02**	V
External Load							
Unipolar Mode			**+1.5**			**+1.5**	mA
Bipolar Mode			**+0.5**			**+0.5**	mA
POWER SUPPLIES							
Power Supply Rejection							
V_{CC} = +12 V ± 5%		±6				**±6**	LSB
V_{EE} = –12 V ± 5%		±6				**±6**	LSB
V_{DD} = +5 V ± 10%		±6				**±6**	LSB
Operating Current							
I_{CC}		18	**20**		18	**20**	mA
I_{EE}		25	**34**		25	**34**	mA
I_{DD}		8	**12**		8	**12**	mA
Power Consumption		560	745		560	745	mW

NOTES
[1]Adjustable to zero. See Figures 5 and 6.
[2]Includes internal voltage reference error.
[3]Includes internal voltage reference drift.
[4]Excludes internal voltage reference drift.
[5]With maximum external load applied.
*% FSR = percent of full-scale range.

Specifications shown in **boldface** are tested on all devices at final electrical test with worst case supply voltages at T_{MIN}, 25°C and T_{MAX}. Results from those tests are used to calculate outgoing quality levels. All min and max specifications are guaranteed, although only those shown in **boldface** are tested.

Specifications subject to change without notice.

AD679

TIMING SPECIFICATIONS

(All device types T_{MIN} to T_{MAX}, $V_{CC} = +12$ V $\pm$ 5%, $V_{EE} = -12$ V $\pm$ 5%, $V_{DD} = +5$ V $\pm$ 10%)

Parameter	Symbol	Min	Max	Units
$\overline{SC}$ Delay	t_{SC}	50		ns
Conversion Time	t_C		6.3	μs
Conversion Rate[1]	t_{CR}		7.8	μs
Convert Pulse Width	t_{CP}	0.097	3.0	μs
Aperture Delay	t_{AD}	5	20	ns
Status Delay	t_{SD}	0	400	ns
Access Time[2, 3]	t_{BA}	10	100	ns
		10	57[4]	ns
Float Delay[5]	t_{FD}	10	80	ns
Output Delay	t_{OD}		0	ns
Format Setup	t_{FS}	100		ns
$\overline{OE}$ Delay	t_{OE}	20		ns
Read Pulse Width	t_{RP}	195		ns
Conversion Delay	t_{CD}	400		ns
$\overline{EOCEN}$ Delay	t_{EO}	50		ns

NOTES
[1]Includes Acquisition Time.
[2]Measured from the falling edge of $\overline{OE}/\overline{EOCEN}$ (0.8 V) to the time at which the data lines/EOC cross 2.0 V or 0.8 V. See Figure 4.
[3]$C_{OUT} = 100$ pF.
[4]$C_{OUT} = 50$ pF.
[5]Measured from the rising edge of $\overline{OE}/\overline{EOCEN}$ (2.0 V) to the time at which the output voltage changes by 0.5. See Figure 4; $C_{OUT} = 10$ pF.

Specifications subject to change without notice.

ORDERING GUIDE[1]

Model[2]	Package	Temperature Range	Tested and Specified	Package Option[3]
AD679JN	28-Pin Plastic DIP	0°C to +70°C	AC	N-28
AD679KN	28-Pin Plastic DIP	0°C to +70°C	AC + DC	N-28
AD679JD	28-Pin Ceramic DIP	0°C to +70°C	AC	D-28
AD679KD	28-Pin Ceramic DIP	0°C to +70°C	AC + DC	D-28
AD679AD	28-Pin Ceramic DIP	−40°C to +85°C	AC	D-28
AD679BD	28-Pin Ceramic DIP	−40°C to +85°C	AC + DC	D-28
AD679SD	28-Pin Ceramic DIP	−55°C to +125°C	AC	D-28
AD679TD	28-Pin Ceramic DIP	−55°C to +125°C	AC + DC	D-28
AD679AJ	44-Lead Ceramic JLCC	−40°C to +85°C	AC	J-44
AD679BJ	44-Lead Ceramic JLCC	−40°C to +85°C	AC + DC	J-44
AD679SJ	44-Lead Ceramic JLCC	−55°C to +125°C	AC	J-44
AD679TJ	44-Lead Ceramic JLCC	−55°C to +125°C	AC + DC	J-44

NOTES
[1]For parallel read (14-bits) interface to 16-bit buses, see AD779.
[2]For details grade and package offerings screened in accordance with MIL-STD-883, refer to the Analog Devices Miliary Products Databook or current AD679/883B data sheet.
[3]N = Plastic DIP; D = Ceramic DIP; J = J-Leaded Ceramic Chip Carrier.
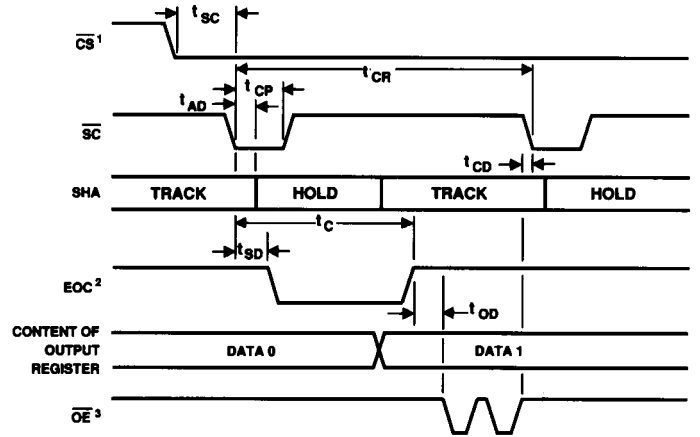
NOTES
[1]IN ASYNCHRONOUS MODE, STATE OF $\overline{CS}$ DOES NOT AFFECT OPERATION. SEE THE START CONVERSION TRUTH TABLE FOR DETAILS.
[2]$\overline{EOCEN}$ = LOW (SEE FIGURE 3). IN SYNCHRONOUS MODE, EOC IS A THREE-STATE OUTPUT. IN ASYNCHRONOUS MODE, EOC IS AN OPEN DRAIN OUTPUT
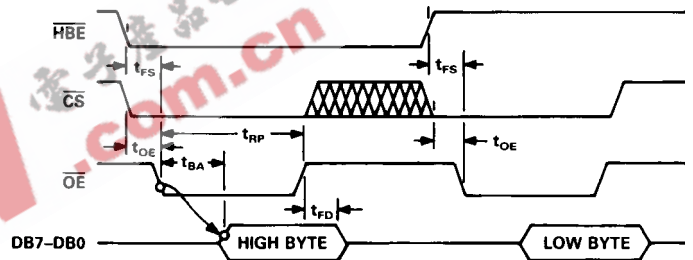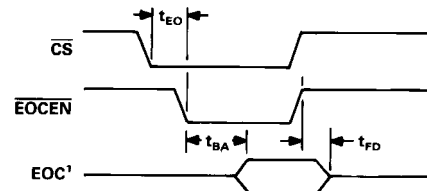[3]DATA SHOULD NOT BE ENABLED DURING A CONVERSION.

Figure 1. Conversion Timing

Figure 2. Output Timing

NOTE
[1]EOC IS A THREE-STATE OUTPUT IN SYNCHRONOUS MODE AND AN OPEN DRAIN OUTPUT IN ASYNCHRO-NOUS. ACCESS (t_{BA}) AND FLOAT (t_{FD}) TIMING SPECIFI-CATIONS DO NOT APPLY IN ASYNCHRONOUS MODE WHERE THEY ARE A FUNCTION THE TIME CONSTANT FORMED BY THE 10 pF OUTPUT CAPACITANCE AND THE PULL-UP RESISTOR.

Figure 3. EOC Timing

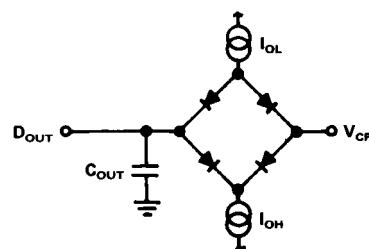| TEST	V_{CP}	C_{OUT}
ACCESS TIME HIGH Z TO LOGIC LOW	5 V	100 pF
FLOAT TIME LOGIC HIGH TO HIGH Z	0 V	10 pF
ACCESS TIME HIGH Z TO LOGIC HIGH	0 V	100 pF
FLOAT TIME LOGIC LOW TO HIGH Z	5 V	10 pF

Figure 4. Load Circuit for Bus Timing Specifications

REV. C

ABSOLUTE MAXIMUM RATINGS*

Specification	With Respect To	Min	Max	Units
V_{CC}	AGND	−0.3	+18	V
V_{EE}	AGND	−18	+0.3	V
V_{CC} (Note 1)	V_{EE}	−0.3	+26.4	V
V_{DD}	DGND	0	+7	V
AGND	DGND	−1	+1	V
AIN, REF_{IN}	AGND	V_{EE}	V_{CC}	V
Digital Inputs	DGND	−0.5	+7	V
Digital Outputs	DGND	−0.5	V_{DD} + 0.3	V
Max Junction Temperature			175	°C

Specification	With Respect To	Min	Max	Units
Operating Temperature				
J and K Grades		0	+70	°C
A and B Grades		−40	+85	°C
S and T Grades		−55	+125	°C
Storage Temperature		−65	+150	°C
Lead Temperature (10 sec max)			+300	°C

NOTES
*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
[1]The AD679 is not designed to operate from ±15 V supplies.

CAUTION

The AD679 features input protection circuitry consisting of large "distributed" diodes and polysilicon series resistors to dissipate both high energy discharges (Human Body Model) and fast, low energy pulses (Charged Device Model). Per Method 3015.2 of MIL-STD-883C, the AD679 has been classified as a Category 1 device.
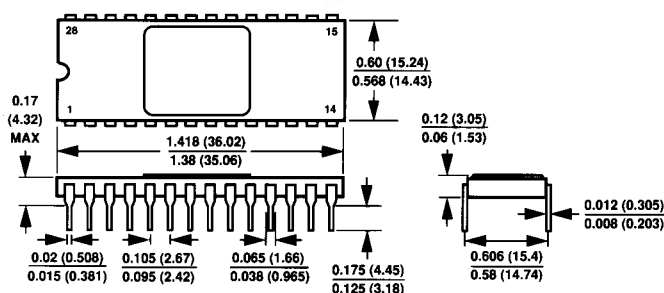
Proper ESD precautions are strongly recommended to avoid functional damage or performance degradation. Charges as high as 4000 volts readily accumulate on the human body and test equipment and discharge without detection. Unused devices must be stored in conductive foam or shunts, and the foam should be discharged to the destination socket before devices are removed. For further information on ESD precautions, refer to Analog Devices' *ESD Prevention Manual.*
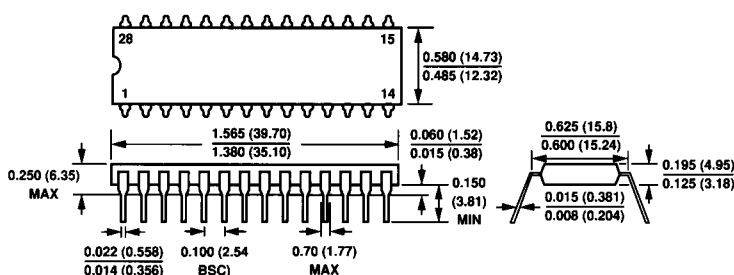
WARNING!

ESD SENSITIVE DEVICE

OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

28-Pin Ceramic DIP Package (D-28)

44-Lead J-Leaded Chip Carrier (J-44)

NOTE
1. PIN 1 INDICATOR IS ON THE BOTTOM OF THE PACKAGE.

28-Lead Plastic DIP Package (N-28)
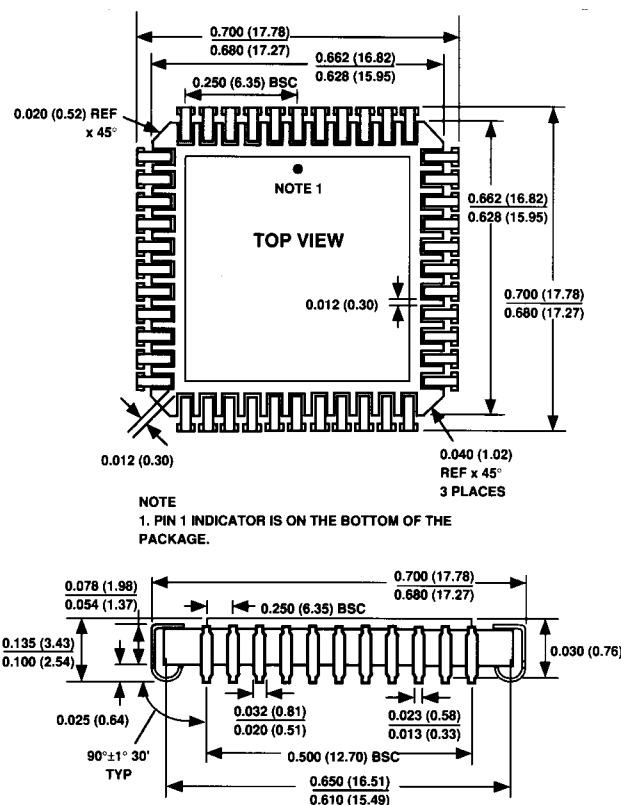
AD679

| Symbol	28-Pin DIP Pin No.	44-Lead JLCC Pin No.	Type	Name and Function
AGND	7	11	P	Analog Ground. This is the ground return for AIN only.
AIN	6	10	AI	Analog Signal Input.
BIPOFF	10	15	AI	Bipolar Offset. Connect to AGND for +10 V input unipolar mode and straight binary output coding. Connect to REF$_{OUT}$ for ±5 V input bipolar mode and twos complement binary output coding.
$\overline{CS}$	4	6	DI	Chip Select. Active LOW.
DGND	12, 14	23	P	Digital Ground.
DB7–DB0	26–19	40, 39, 37, 36, 35, 34, 33, 31	DO	Data Bits. These pins provide all 14 bits in two bytes (8+6 bits). Active HIGH.
EOC	27	42	DO	End-of-Convert. EOC goes LOW when a conversion starts and goes HIGH when the conversion finishes. In asynchronous mode, EOC is an open drain output and requires an external 3 kΩ pull-up resistor. See $\overline{EOCEN}$ and SYNC pins for information on EOC gating.
$\overline{EOCEN}$	1	1	DI	End-of-Convert Enable. Enables EOC pin. Active LOW.
$\overline{HBE}$	15	25	DI	High Byte Enable. If LOW, output contains high byte. If HIGH, output contains low byte (corresponding to the most recently read high byte).
$\overline{OE}$	2	3	DI	Output Enable. A down-going transition on $\overline{OE}$ enables DB7–DB0. Gated with $\overline{CS}$. Active LOW.
REF$_{IN}$	9	14	AI	Reference Input. +5 V input gives 10 V full-scale range.
REF$_{OUT}$	8	12	AO	+5 V Reference Output. Tied to REF$_{IN}$ for normal operation.
$\overline{SC}$	3	5	DI	Start Convert. Active LOW. See SYNC pin for gating.
SYNC	13	21	DI	SYNC Control. If tied to V$_{DD}$ (synchronous mode), $\overline{SC}$ and $\overline{EOCEN}$ are gated by $\overline{CS}$. If tied to DGND (asynchronous mode), $\overline{SC}$ and $\overline{EOCEN}$ are independent of $\overline{CS}$, and EOC is an open drain output. EOC requires an external 3 kΩ pull-up resistor in asynchronous mode.
V$_{CC}$	11	17	P	+12 V Analog Power.
V$_{EE}$	5	8	P	–12 V Analog Power.
V$_{DD}$	28	43	P	+5 V Digital Power.
—	16		U	Tie to DGND.
—	17–18	2, 4, 7, 9, 13, 16, 18, 19, 20, 22, 24, 26, 27, 28, 29, 30, 32, 38, 41, 44	U	These pins are unused and should be connected to DGND or V$_{DD}$.

Type: AI = Analog Input. AO = Analog Output. DI = Digital Input (TTL and 5 V CMOS compatible). DO = Digital Output (TTL and 5 V CMOS compatible). All DO pins are three-state drivers. P = Power. U = Unused.

PIN CONFIGURATION

DIP Package

JLCC Package

NC = NO CONNECT

REV. C
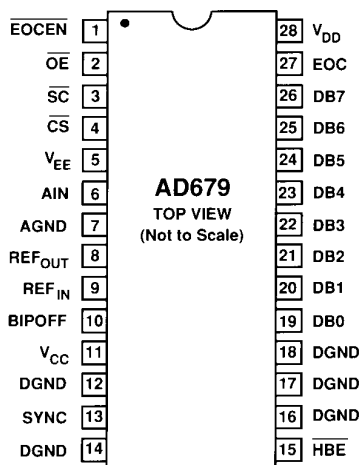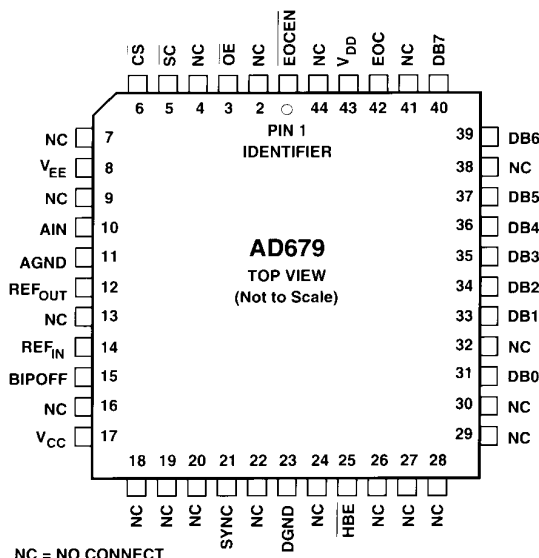
NYQUIST FREQUENCY
An implication of the Nyquist sampling theorem, the "Nyquist Frequency" of a converter is that input frequency which is one-half the sampling frequency of the converter.

SIGNAL-TO-NOISE AND DISTORTION (S/N+D) RATIO
S/N+D is the ratio of the rms value of the measured input signal to the rms sum of all other spectral components below the Nyquist frequency, including harmonics but excluding dc.

TOTAL HARMONIC DISTORTION (THD)
THD is the ratio of the rms sum of the first six harmonic components to the rms value of a full-scale input signal and is expressed as a percentage or in decibels. For input signals or harmonics that are above the Nyquist frequency, the aliased component is used.

PEAK SPURIOUS OR PEAK HARMONIC COMPONENT
The peak spurious or peak harmonic component is the largest spectral component excluding the input signal and dc. This value is expressed in decibels relative to the rms value of a full-scale input signal.

INTERMODULATION DISTORTION (IMD)
With inputs consisting of sine waves at two frequencies, fa and fb, any device with nonlinearities will create distortion products, of order (m + n), at sum and difference frequencies of mfa ± nfb, where m, n = 0, 1, 2, 3. . . . Intermodulation terms are those for which m or n is not equal to zero. For example, the second order terms are (fa + fb) and (fa – fb) and the third order terms are (2 fa + fb), (2 fa – fb), (fa + 2 fb) and (fa – 2 fb). The IMD products are expressed as the decibel ratio of the rms sum of the measured input signals to the rms sum of the distortion terms. The two signals applied to the converter are of equal amplitude and the peak value of their sum is –0.5 dB from full-scale (9.44 V p-p). The IMD products are normalized to a 0-dB input signal.

BANDWIDTH
The full-power bandwidth is that input frequency at which the amplitude of the reconstructed fundamental is reduced by 3 dB for a full-scale input.

The full-linear bandwidth is the input frequency at which the slew rate limit of the sample-hold-amplifier (SHA) is reached. At this point, the amplitude of the reconstructed fundamental has degraded by less than –0.1 dB. Beyond this frequency, distortion of the sampled input signal increases significantly.

The AD679 has been designed to optimize input bandwidth, allowing it to undersample input signals with frequencies significantly above the converter's Nyquist frequency.

APERTURE DELAY
Aperture delay is a measure of the SHA's performance and is measured from the falling edge of Start Convert ($\overline{SC}$) to when the input signal is held for conversion. In synchronous mode, Chip Select ($\overline{CS}$) should be LOW before $\overline{SC}$ to minimize aperture delay.

APERTURE JITTER
Aperture jitter is the variation in aperture delay for successive samples and is manifested as noise on the input to the A/D.

INPUT SETTLING TIME
Settling time is a function of the SHA's ability to track fast slewing signals. This is specified as the maximum time required in track mode after a full-scale step input to guarantee rated conversion accuracy.

DIFFERENTIAL NONLINEARITY (DNL)
In an ideal ADC, code transitions are 1 LSB apart. Differential linearity is the deviation from this ideal value. It is often specified in terms of resolution for which no missing codes (NMC) are guaranteed.

INTEGRAL NONLINEARITY (INL)
The ideal transfer function for a linear ADC is a straight line drawn between "zero" and "full scale." The point used as "zero" occurs 1/2 LSB before the first code transition. "Full scale" is defined as a level 1 1/2 LSB beyond the last code transition. Integral linearity error is the worst case deviation of a code from the straight line. The deviation of each code is measured from the middle of that code.

Note that the linearity error is not user adjustable.

POWER SUPPLY REJECTION
Variations in power supply will affect the full-scale transition, but not the converter's linearity. Power Supply Rejection is the maximum change in the full-scale transition point due to a change in power supply voltage from the nominal value.

TEMPERATURE DRIFT
This is the maximum change in the parameter from the initial value (@ +25°C) to the value at T_{MIN} or T_{MAX}.

UNIPOLAR ZERO ERROR
In unipolar mode, the first transition should occur at a level 1/2 LSB above analog ground. Unipolar zero error is the deviation of the actual transition from that point. This error can be adjusted as discussed in the Input Connections and Calibration section.

BIPOLAR ZERO ERROR
In the bipolar mode, the major carry transition (11 1111 1111 1111 to 00 0000 0000 0000) should occur at an analog value 1/2 LSB below analog ground. Bipolar zero error is the deviation of the actual transition from that point. This error can be adjusted as discussed in the Input Connections and Calibration section.

GAIN ERROR
The last transition should occur at an analog value 1 1/2 LSB below the nominal full scale (9.9991 volts for a 0 V–10 V range, 4.9991 volts for a ±5 V range). The gain error is the deviation of the actual level at the last transition from the ideal level with the zero error trimmed out. This error can be adjusted as shown in the Input Connections and Calibration section.

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CONVERSION CONTROL

In synchronous mode (SYNC = HIGH), both Chip Select ($\overline{CS}$) and Start Convert ($\overline{SC}$) must be brought LOW to start a conversion. $\overline{CS}$ should be LOW t_{SC} before $\overline{SC}$ is brought LOW. In asynchronous mode (SYNC = LOW), a conversion is started by bringing $\overline{SC}$ low, regardless of the state of $\overline{CS}$.

Before a conversion is started, End-of-Convert (EOC) is HIGH and the sample-hold is in track mode. After a conversion is started, the sample-hold goes into hold mode and EOC goes LOW, signifying that a conversion is in progress. During the conversion, the sample-hold will go back into track mode and start acquiring the next sample.

In track mode, the sample-hold will settle to ±0.003% (14 bits) in 1.5 µs maximum. The acquisition time does not affect the throughput rate as the AD679 goes back into track mode more than 2 µs before the next conversion. In multichannel systems, the input channel can be switched as soon as EOC goes LOW.

Bringing $\overline{OE}$ LOW t_{OE} after $\overline{CS}$ goes LOW makes the output register contents available on the output data bits (DB7–DB0). A period of time t_{CD} is required after $\overline{OE}$ is brought HIGH before the next SC instruction is issued.

If $\overline{SC}$ is held LOW, conversion accuracy may deteriorate. For this reason, $\overline{SC}$ should not be held low in an attempt to operate in a continuously converting mode.

START CONVERSION TRUTH TABLE

		INPUTS		STATUS
	SYNC	$\overline{CS}$	$\overline{SC}$	
Synchronous Mode	1	1	X	No Conversion
	1	0	ſ	Start Conversion
	1	ſ	0	Start Conversion (Not Recommended)
	1	0	0	Continuous Conversion (Not Recommended)
Asynchronous Mode	0	X	1	No Conversion
	0	X	ſ	Start Conversion
	0	X	0	Continuous Conversion (Not Recommended)

NOTES
1 = HIGH voltage level.
0 = LOW voltage level.
X = Don't care.
ſ = HIGH to LOW transition. Must stay low for t = t_{CP}.

14-BIT MODE CODING FORMAT (1 LSB = 0.61 mV)

Unipolar Coding (Straight Binary)		Bipolar Coding (Twos Complement)	
$V_{IN}\star$	Output Code	$V_{IN}\star$	Output Code
0.00000 V	000 . . . 0	−5.00000 V	100 . . . 0
5.00000 V	100 . . . 0	−0.00061 V	111 . . . 1
9.99939 V	111 . . . 1	0.00000 V	000 . . . 0
		+2.50000 V	010 . . . 0
		+4.99939 V	011 . . . 1

$\star$Code center.

END-OF-CONVERT

In asynchronous mode, End-of-Convert (EOC) is an open drain output (requiring a minimum 3 kΩ pull-up resistor) enabled by End-of-Convert Enable ($\overline{EOCEN}$). In synchronous mode, EOC is a three-state output which is enabled by $\overline{EOCEN}$ and $\overline{CS}$. See Conversion Status Truth Table. Access (t_{BA}) and float (t_{FD}) timing specifications do not apply in asynchronous mode where they are a function of the time constant formed by the external load capacitance and the pull-up resistor.

OUTPUT ENABLE OPERATION

The data bits (DB7–DB0) are three-state outputs that are enabled by Chip Select ($\overline{CS}$) and Output Enable ($\overline{OE}$). $\overline{CS}$ should be LOW t_{OE} before $\overline{OE}$ is brought LOW.

When EOC goes HIGH, the conversion is completed and the output data may be read. The output is read in two steps as a 16-bit word, with the high byte read first, followed by the low byte. High Byte Enable ($\overline{HBE}$) controls the output sequence. The 14-bit result is left justified within the 16-bit field.

In unipolar mode (BIPOFF tied to AGND), the output coding is straight binary. In bipolar mode (BIPOFF tied to REF$_{OUT}$), output coding is twos-complement binary.

POWER-UP

The AD679 typically requires 10 µs after power-up to reset internal logic.

CONVERSION STATUS TRUTH TABLE

	INPUTS			OUTPUT	
	SYNC	$\overline{CS}$	$\overline{EOCEN}$	EOC	STATUS
Synchronous Mode	1	0	0	0	Converting
	1	0	0	1	Not Converting
	1	1	X	High Z	Either
	1	X	1	High Z	Either
Asynchronous Mode*	0	X	0	0	Converting
	0	X	0	High Z	Not Converting
	0	X	1	High Z	Either

NOTES
1 = HIGH voltage level.
0 = LOW voltage level.
X = Don't care.
*EOC requires a pull-up resistor in asynchronous mode.

OUTPUT ENABLE TRUTH TABLE

	INPUTS		OUTPUTS
	$\overline{HBE}$	($\overline{CS}$ U $\overline{OE}$)	DB7 . . . DB0
	X	1	← High Z →
Unipolar or Bipolar	0	0	a b c d e f g h
	1	0	i j k l m n 0 0

NOTES
1 = HIGH voltage level.   a = MSB.
0 = LOW voltage level.   n = LSB.
X = Don't care.
U = Logical OR.
Data coding is binary for Unipolar Mode and 2s Complement Binary for Bipolar Mode.

INPUT CONNECTIONS AND CALIBRATION

The high (10 MΩ) input impedance of the AD679 eases the task of interfacing to high source impedances or multiplexer channel-to-channel mismatches of up to 300 Ω. The 10 V p-p full-scale input range accepts the majority of signal voltages without the need for voltage divider networks which could deteriorate the accuracy of the ADC.

The AD679 is factory trimmed to minimize offset, gain and linearity errors. In unipolar mode, the only external component that is required is a 50 Ω ±1% resistor. Two resistors are required in bipolar mode. If offset and gain are not critical (as in some ac applications), even these components can be eliminated.

In some applications, offset and gain errors need to be trimmed out completely. The following sections describe the correct procedure for these various situations.

BIPOLAR RANGE INPUTS

The connections for the bipolar mode are shown in Figure 5. In this mode, data output coding will be twos complement binary. This circuit will allow approximately ±25 mV of offset trim range (±40 LSB) and ±0.5% of gain trim range (±80 LSB).

Either or both of the trim pots can be replaced with 50 Ω ±1% fixed resistors if the AD679 accuracy limits are sufficient for application. If the pins are shorted together, the additional offset and gain errors will be approximately 80 LSB.

To trim bipolar zero to its nominal value, apply a signal 1/2 LSB below midrange (–0.305 mV for a ±5 V range) and adjust R1 until the major carry transition is located (11 1111 1111 1111 to 00 0000 0000 0000). To trim the gain, apply a signal 1 1/2 LSB below full scale (+4.9991 V for a ±5 V range) and adjust R2 to give the last positive transition (01 1111 1111 1110 to 01 1111 1111 1111). These trims are interactive so several iterations may be necessary for convergence.

A single pass calibration can be done by substituting a bipolar offset trim (error at minus full scale) for the bipolar zero trim (error at midscale), using the same circuit. First, apply a signal 1/2 LSB above minus full scale (–4.9997 V for a ±5 V range) and adjust R1 until the minus full-scale transition is located (10 0000 0000 0000 to 10 000 000 0001). Then perform the gain error trim as outlined above.
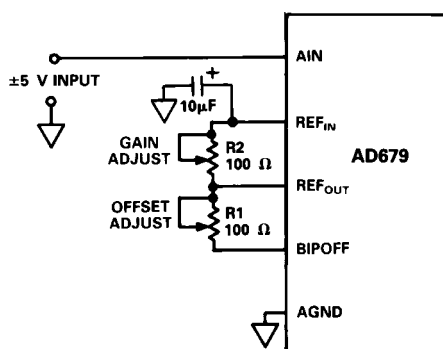

Figure 5. Bipolar Input Connections with Gain and Offset Trims

UNIPOLAR RANGE INPUTS

Offset and gain errors can be trimmed out by using the configuration shown in Figure 6. This circuit allows approximately ±25 mV of offset trim range (±40 LSB) and ±0.5% of gain trim range (±80 LSB).

The nominal offset is 1/2 LSB so that the analog range that corresponds to each code will be centered in the middle of that code (halfway between the transitions to the codes above and below it). Thus the first transition (from 00 0000 0000 0000 to 00 0000 0000 0001) should nominally occur for an input level of +1/2 LSB (0.305 mV above ground for a 10 V range). To trim unipolar zero to this nominal value, apply a 0.305 mV signal to AIN and adjust R1 until the first transition is located.

The gain trim is done by adjusting R2. If the nominal value is required, apply a signal 1 1/2 LSB below full scale (9.9997 V for a 10 V range) and adjust R2 until the last transition is located (11 1111 1111 1110 to 11 1111 1111 1111).

If offset adjustment is not required, BIPOFF should be connected directly to AGND. If gain adjustment is not required, R2 should be replaced with a fixed 50 Ω ±1% metal film resistor. If REF$_{OUT}$ is connected directly to REF$_{IN}$, the additional gain error will be approximately 1%.
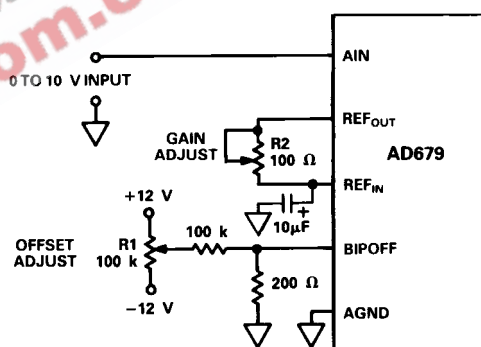

Figure 6. Unipolar Input Connections with Gain and Offset Trims

REFERENCE DECOUPLING

It is recommended that a 10 μF tantalum capacitor be connected between REF$_{IN}$ (Pin 9) and ground. This has the effect of improving the S/N+D ratio through filtering possible broadband noise contributions from the voltage reference.

BOARD LAYOUT

Designing with high resolution data converters requires careful attention to board layout. Trace impedance is a significant issue. A 1.22 mA current through a 0.5 Ω trace will develop a voltage drop of 0.6 mV, which is 1 LSB at the 14 bit level for a 10 V full-scale span. In addition to ground drops, inductive and capacitive coupling need to be considered, especially when high accuracy analog signals share the same board with digital signals. Finally, power supplies need to be decoupled in order to filter out ac noise.

Analog and digital signals should not share a common path. Each signal should have an appropriate analog or digital return routed close to it. Using this approach, signal loops enclose a small area, minimizing the inductive coupling of noise. Wide PC tracks, large gauge wire, and ground planes are highly recommended to provide low impedance signal paths. Separate analog

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and digital ground planes are also desirable, with a single inter-connection point to minimize ground loops. Analog signals should be routed as far as possible from digital signals and should cross them at right angles.

The AD679 incorporates several features to help the user's lay-out. Analog pins (V_{EE}, AIN, AGND, REF_{OUT}, REF_{IN}, BIPOFF, V_{CC}) are adjacent to help isolate analog from digital signals. In addition, the 10 MΩ input impedance of AIN minimizes input trace impedance errors. Finally, ground currents have been minimized by careful circuit architecture. Current through AGND is 200 µA, with no code dependent variation. The cur-rent through DGND is dominated by the return current for DB7–DB0 and EOC.

SUPPLY DECOUPLING
The AD679 power supplies should be well filtered, well regu-lated, and free from high frequency noise. Switching power sup-plies are not recommended due to their tendency to generate spikes which can induce noise in the analog system.

Decoupling capacitors should be used in very close layout prox-imity between all power supply pins and analog ground. A 10 µF tantalum capacitor in parallel with a 0.1 µF ceramic capacitor provides adequate decoupling.

An effort should be made to minimize the trace length between the capacitor leads and the respective converter power supply and common pins. The circuit layout should attempt to locate the AD679, associated analog input circuitry and interconnec-tions as far as possible from logic circuitry. A solid analog ground plane around the AD679 will isolate large switching ground currents. For these reasons, the use of wire wrap circuit construction is not recommended; careful printed circuit con-struction is preferred.

GROUNDING
If a single AD679 is used with separate analog and digital ground planes, connect the analog ground plane to AGND and the digital ground plane to DGND keeping lead lengths as short as possible. Then connect AGND and DGND together at the AD679. If multiple AD679s are used or the AD679 shares ana-log supplies with other components, connect the analog and digital returns together once at the power supplies rather than at each chip. This prevents large ground loops which inductively couple noise and allow digital currents to flow through the ana-log system.

USE OF EXTERNAL VOLTAGE REFERENCE
The AD679 features an on-chip voltage reference. For improved gain accuracy over temperature, a high performance external voltage reference may be used in place of the on-chip reference.

The AD586 and AD588 are popular references appropriate for use with high resolution converters. The AD586 is a low cost reference which utilizes a buried Zener architecture to provide low noise and drift. The AD588 is a higher performance refer-ence which uses a proprietary implanted buried Zener diode in conjunction with laser-trimmed thin-film resistors for low offset and low drift.

Figure 7 shows the use of the AD586 with the AD679 in a bipo-lar input mode. Over the 0°C to +70°C range, the AD586 L-grade exhibits less than a 2.25 mV output change from its ini-

tial value at 25°C. REF_{IN} (Pin 9) scales its input by a factor of two; thus, this change becomes effectively 4.5 mV. When ap-plied to the AD679, this results in a total gain drift of 0.09% FSR, which is an improvement over the on-chip reference per-formance of 0.11% FSR. A noise-reduction capacitor, C_N, has been shown.

This capacitor reduces the broadband noise of the AD586 out-put, thereby optimizing the overall ac and dc performance of the AD679.
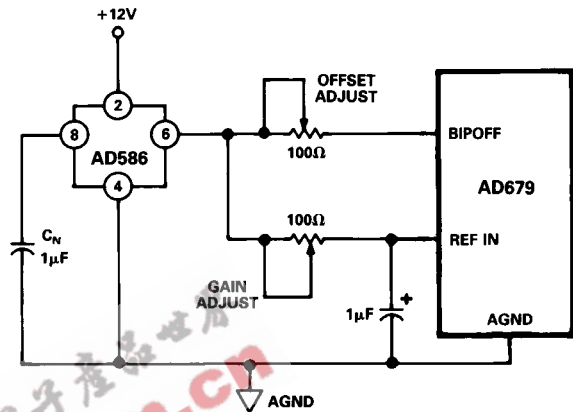

Figure 7. Bipolar Input with Gain and Offset Trims

Figure 8 shows the AD679 in unipolar input mode with the AD588 reference. The AD588 output is accurate to 0.65 mV from its value at 25°C over the 0°C to 70°C range. This results in a 0.06% FSR total gain drift for the AD679, which is a sub-stantial improvement over the on-chip reference performance of 0.11% FSR. A noise-reduction network on Pins 4, 6 and 7 has been shown. The 1 µF capacitors form low pass filters with the internal resistance of the AD588 Zener and amplifier cells and external resistance. This reduces the high frequency (to 1 MHz) noise of the AD588, providing optimum ac and dc performance of the AD679.
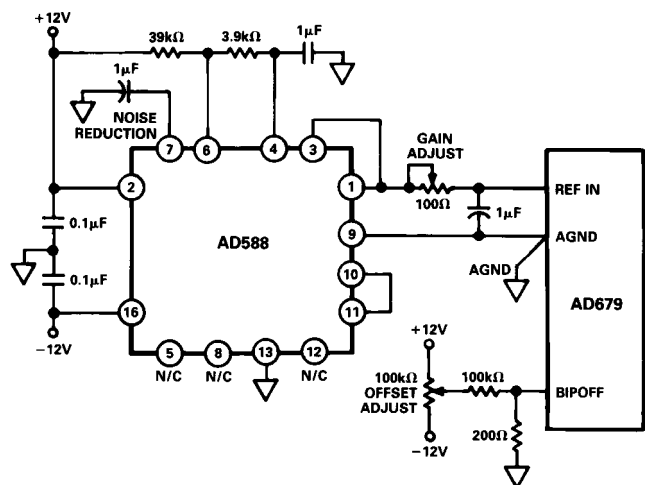

Figure 8. Unipolar Input with Gain and Offset Trims

INTERFACING THE AD679 TO MICROPROCESSORS
The I/O capabilities of the AD679 allow direct interfacing to general purpose and DSP microprocessor buses. The asynchro-nous conversion control feature allows complete flexibility and control with minimal external hardware.

The following examples illustrate typical AD679 interface configurations.

AD679 to TMS320C25

In Figure 9 the AD679 is mapped into the TMS320C25 I/O space. AD679 conversions are initiated by issuing an OUT instruction to Port 1. EOC status and the conversion result are read in with an IN instruction to Port 1. A single wait state is inserted by generating the processor READY input from $\overline{IS}$, Port 1 and $\overline{MSC}$. Address line A0 provides $\overline{HBE}$ decoding to select between the high and low bytes of data. This configuration supports processor clock speeds of 20 MHz and is capable of supporting processor clock speeds of 40 MHz if a NOP instruction follows each AD679 read instruction.
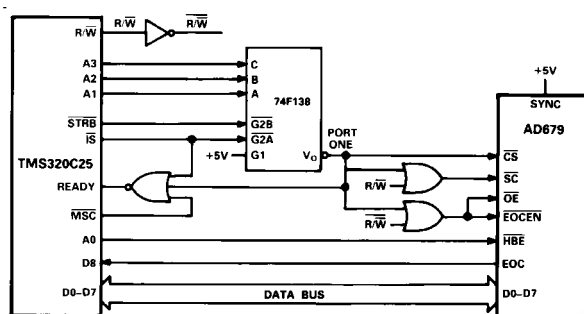
Figure 9. AD679 to TMS320C25 Interface

AD679 to 80186

Figure 10 shows the AD679 interfaced to the 80186 microprocessor. This interface allows the 80186's built-in DMA controller to transfer the AD679 output into a RAM based FIFO buffer of any length, with no microprocessor intervention.

In this application the AD679 is configured in the asynchronous mode, which allows conversions to be initiated by an external trigger source independent of the microprocessor clock. After each conversion, the AD679 EOC signal generates a DMA request to Channel 1 (DRQ1). The subsequent DMA READ sequences the high and low byte AD679 data and resets the interrupt latch. The system designer must assign a sufficient priority to the DMA channel to ensure that the DMA request will be serviced before the completion of the next conversion. This configuration can be used with 6 MHz and 8 MHz 80186 processors.
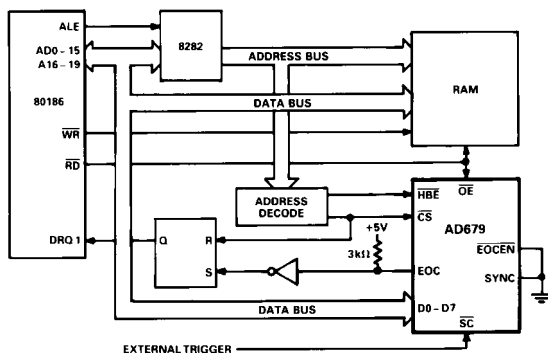

Figure 10. AD679 to 80186 DMA Interface

AD679 to Analog Devices ADSP-2101

Figure 11 demonstrates the AD679 interfaced to an ADSP-2101. With a clock frequency of 12.5 MHz, and instruction execution in one 80 ns cycle, the digital signal processor supports the AD679 interface with one wait state.

The converter is configured to run asynchronously using a sampling clock. The EOC output of the AD679 gets asserted at the end of each conversion and causes an interrupt. Upon interrupt, the ADSP-2101 immediately asserts its FO pin LOW. In the following cycle, the processor starts a data memory read by providing an address on the DMA bus. The decoded address generates $\overline{OE}$ for the converter, and the high byte of the conversion result is read over the data bus. The read operation is extended with one wait state and thus started and completed within two processor cycles (160 ns). Next, the ADSP-2101 asserts its FO HIGH. This allows the processor to start reading the lower byte of data. This read operation executes in a similar manner to the first and is completed during the next 160 ns.
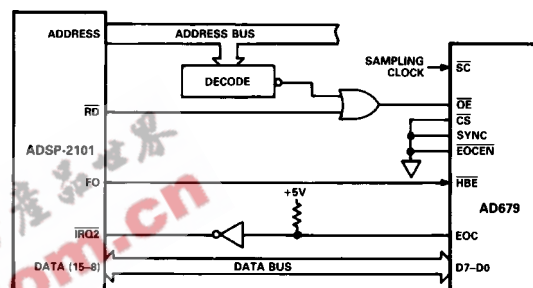

Figure 11. AD679 to ADSP-2101 Interface

AD679 to Analog Devices ADSP-2100A

Figure 12 demonstrates the AD679 interfaced to an ADSP-2100A. With a clock frequency of 12.5 MHz, and instruction execution in one 80 ns cycle, the digital signal processor will support the AD679 data memory interface with three hardware wait states.

The converter is configured to run asynchronously using a sampling clock. The EOC output of the AD679 gets asserted at the end of each conversion and causes an interrupt. Upon interrupt, the ADSP-2100A immediately executes a data memory write instruction which asserts $\overline{HBE}$. In the following cycle, the processor starts a data memory read (high byte read) by providing an address on the DMA bus. The decoded address generates $\overline{OE}$ for the converter. $\overline{OE}$, together with logic and latch, is used to force the ADSP-2100A into a one cycle wait state by generating DMACK. The read operation is thus started and completed within two processor cycles (160 ns). $\overline{HBE}$ is released during "high byte read." This allows the processor to read the lower byte of data as soon as "high byte read" is complete. The low byte read operation executes in a similar manner to the first and is completed during the next 160 ns.
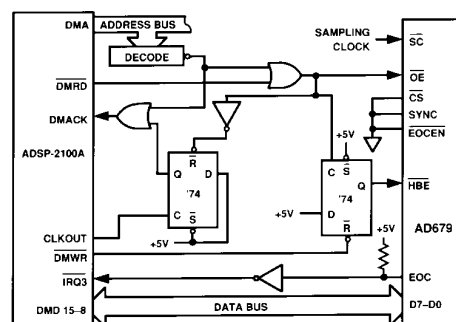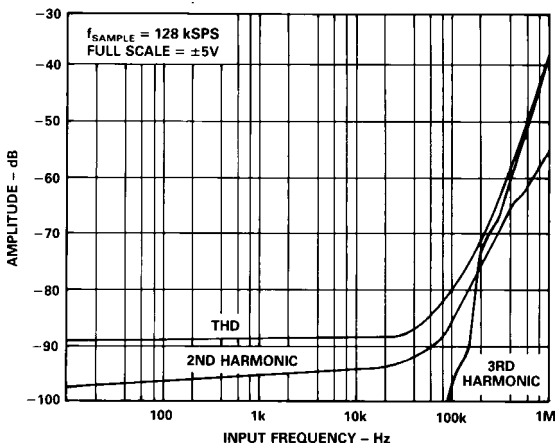

Figure 12. AD679 to ADSP-2100A Interface

AD679

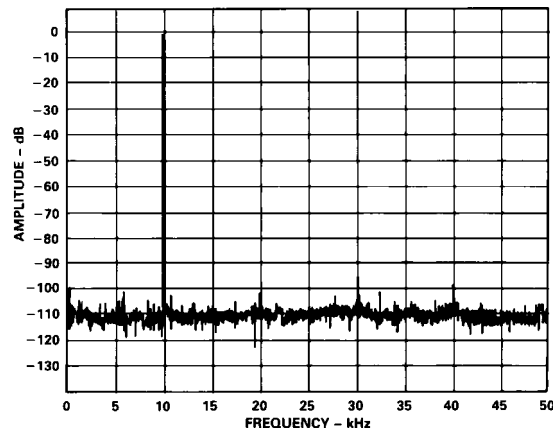Figure 13. Harmonic Distortion vs. Input Frequency (–0.5 dB Input)

Figure 14. Total Harmonic Distortion vs. Input Frequency and Amplitude

Figure 15. S/(N+D) vs. Input Frequency and Amplitude

Figure 16. 5-Plot Averaged 2048 Point FFT at 128 kSPS, $f_{IN} = 10.009$ kHz
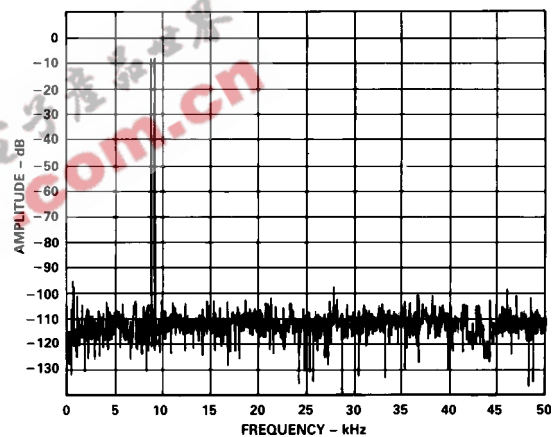
Figure 17. Nonaveraged IMD Plot for $f_{IN} = 9.08$ kHz (f_a), 9.58 kHz (f_b) at 128 kSPS
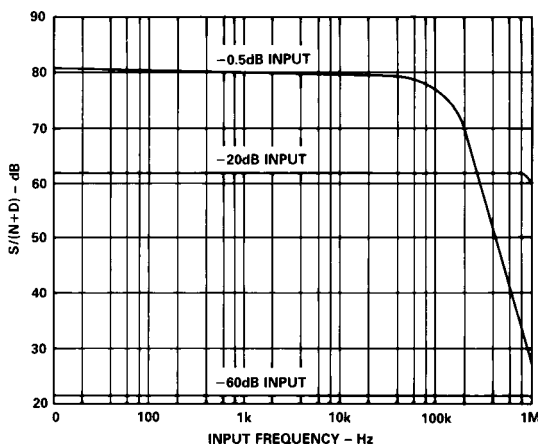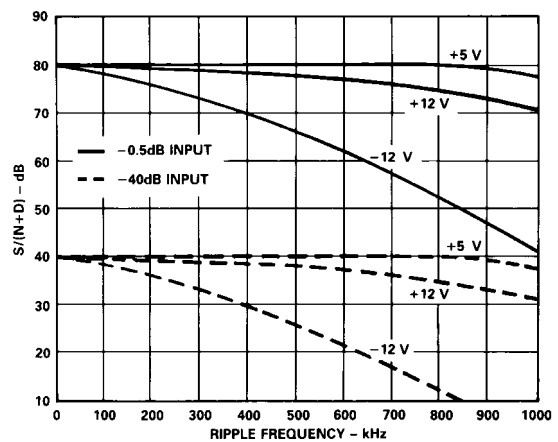

Figure 18. Power Supply Rejection ($f_{IN} = 10$ kHz, $f_{SAMPLE} = 128$ kSPS, $V_{RIPPLE} = 0.1$ V p-p)

–12–

REV. C